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Substitute for form 1449/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet

1

of

2

Complete if Known

Application Number	10/617,767
Filing Date	July 14, 2003
First Named Inventor	Jung-hyun LEE, et al
Art Unit	2822
Examiner Name	C. L. NOVACEK
Attorney Docket Number	249/349

U. S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	T ^o
		Country Code ³ ~ Number ⁴ ~ Kind Code ⁵ (If known)				
OK		EP 0 540 994 A1	05-12-1993	ARGOS, et al.		
OK		EP 1 341 217 A2	09-03-2003	LEE, et al.	Entered 1/4/05	
OK		WO 02/31875 A2/A3	04-18-2002	HAUKKA, et al.		
OK		JP 2001-267566 *	09-28-2001	MA, et al.	Entered 1/4/05	
		*=US 6,407,435				

**Examiner
Signature**

Christy Kovacek

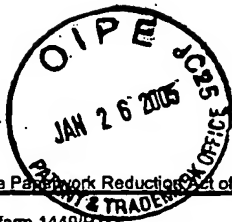
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Sheet 2 of 2

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
CX	1	CHOI, et al., *, Jpn. J. of Applied Physics, 40(4B, Part 1):2940-2942, (April 2001)	
		* Entitled: "Electrical Characteristics of Pt/SrBi ₂ Ta ₂ O ₉ /Ta ₂ O ₅ /Si Using Ta ₂ O ₅ as the Buffer Layer"	
CX	2	CLARK-PHELPS, et al. **, Mat. Res. Soc. Symp. Proc. Vol. 670, Society, K2.2.1-6 (2001)	
		** Entitled: "Engineered tantalum aluminate and hafnium aluminate ALD films for ultrathin ... "	
CX	3	WILK, et al., ***, Journal of Applied Physics, Vol. 89, No. 10:5243-5275, (May 15, 2001)	
		***Entitled: "High-k gate dielectrics: Current status and materials properties considerations"	

Examiner Signature	<i>Christy Novacek</i>	Date Considered	3/28/05
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